

# SIHF22N60E-GE3

#### SIHF22N60E-GE3 Information

www.elsener.com	 SIHF22N60E-GE3 Vishay Siliconix Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single MOSFET N-CH 600V 21A TO220 TO-220-3 Full Pack For the pricing/inventory/lead time, please contact us	
For Reference Only	Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

## **Certified Quality**

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



## SIHF22N60E-GE3 Specifications

Manufacturer Part Number	SIHF22N60E-GE3
Manufacturer	Vishay Siliconix
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-220-3 Full Pack
Series	Ε
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	600V
Current - Continuous Drain (Id) @ 25°C	21A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	86nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	1920pF @ 100V
Vgs (Max)	$\pm 30 V$
FET Feature	-
Power Dissipation (Max)	35W (Tc)
Rds On (Max) @ Id, Vgs	180 mOhm @ 11A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	TO-220 Full Pack
Package / Case	TO-220-3 Full Pack
	Report errors?

#### SIHF22N60E-GE3 Guarantees



**Quality Guarantees** 

We provide 90 days warranty. \* If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



#### **Service Guarantees**

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

#### SIHF22N60E-GE3 Payment Methods



### SIHF22N60E-GE3 Shipping Methods



If you have any question about SIHF22N60E-GE3, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com